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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Obsolete
Core Processor	RL78
Core Size	16-Bit
Speed	24MHz
Connectivity	CSI, I <sup>2</sup> C, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	14
Program Memory Size	4KB (4K x 8)
Program Memory Type	FLASH
EEPROM Size	2K x 8
RAM Size	512 x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 5.5V
Data Converters	A/D 11x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	20-LSSOP (0.173", 4.40mm Width)
Supplier Device Package	20-LSSOP
Purchase URL	<a href="https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f10267gsp-v5">https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f10267gsp-v5</a>

## (2) 30-pin products

 $(T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )

(2/2)

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit	
Supply current <sup>Note 1</sup>	I <sub>DD2</sub> <sup>Note 2</sup>	HALT mode	HS (High-speed main) mode <sup>Note 6</sup>	f <sub>IH</sub> = 24 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		440	1280	μA	
					V <sub>DD</sub> = 3.0 V		440	1280		
				f <sub>IH</sub> = 16 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		400	1000	μA	
					V <sub>DD</sub> = 3.0 V		400	1000		
				LS (Low-speed main) mode <sup>Note 6</sup>	f <sub>IH</sub> = 8 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 3.0 V		260	530	μA
						V <sub>DD</sub> = 2.0 V		260	530	
			HS (High-speed main) mode <sup>Note 6</sup>	f <sub>MX</sub> = 20 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 5.0 V	Square wave input		280	1000	μA	
					Resonator connection		450	1170		
				f <sub>MX</sub> = 20 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		280	1000	μA	
					Resonator connection		450	1170		
				f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 5.0 V	Square wave input		190	600	μA	
					Resonator connection		260	670		
				f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		190	600	μA	
					Resonator connection		260	670		
			LS (Low-speed main) mode <sup>Note 6</sup>	f <sub>MX</sub> = 8 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		95	330	μA	
					Resonator connection		145	380		
				f <sub>MX</sub> = 8 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 2.0 V	Square wave input		95	330	μA	
					Resonator connection		145	380		
	I <sub>DD3</sub> <sup>Note 5</sup>	STOP mode	T <sub>A</sub> = −40°C					0.18	0.50	μA
			T <sub>A</sub> = +25°C					0.23	0.50	
			T <sub>A</sub> = +50°C					0.30	1.10	
			T <sub>A</sub> = +70°C					0.46	1.90	
			T <sub>A</sub> = +85°C					0.75	3.30	

**Notes** 1. Total current flowing into  $V_{DD}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$  or  $V_{SS}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.

2. During HALT instruction execution by flash memory.

3. When high-speed on-chip oscillator clock is stopped.

4. When high-speed system clock is stopped.

5. Not including the current flowing into the 12-bit interval timer and watchdog timer.

6. Relationship between operation voltage width, operation frequency of CPU and operation mode is as follows.

HS (High speed main) mode:  $V_{DD} = 2.7\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $24\text{ MHz}$

$V_{DD} = 2.4\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $16\text{ MHz}$

LS (Low speed main) mode:  $V_{DD} = 1.8\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $8\text{ MHz}$

**Remarks** 1.  $f_{MX}$ : High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

2.  $f_{IH}$ : high-speed on-chip oscillator clock frequency

3. Except STOP mode, temperature condition of the TYP. value is  $T_A = 25^\circ\text{C}$ .

## 2.4 AC Characteristics

(TA = -40 to +85°C, 1.8 V ≤ VDD ≤ 5.5 V, VSS = 0 V)

Items	Symbol	Conditions			MIN.	TYP.	MAX.	Unit
Instruction cycle (minimum instruction execution time)	T <sub>CY</sub>	Main system clock (f <sub>MAIN</sub> ) operation	HS (High-speed main) mode	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.04167		1	μs
				2.4 V ≤ V <sub>DD</sub> < 2.7 V	0.0625		1	μs
			LS (Low-speed main) mode	1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.125		1	μs
		During self programming	HS (High-speed main) mode	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.04167		1	μs
				2.4 V ≤ V <sub>DD</sub> < 2.7 V	0.0625		1	μs
			LS (Low-speed main) mode	1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.125		1	μs
External main system clock frequency	f <sub>EX</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V			1.0		20.0	MHz
		2.4 V ≤ V <sub>DD</sub> < 2.7 V			1.0		16.0	MHz
		1.8 V ≤ V <sub>DD</sub> < 2.4 V			1.0		8.0	MHz
External main system clock input high-level width, low-level width	t <sub>EXH</sub> , t <sub>EXL</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V			24			ns
		2.4 V ≤ V <sub>DD</sub> < 2.7 V			30			ns
		1.8 V ≤ V <sub>DD</sub> < 2.4 V			60			ns
TI00 to TI07 input high-level width, low-level width	t <sub>TIH</sub> , t <sub>TIL</sub>				1/f <sub>MCK</sub> + 10			ns
TO00 to TO07 output frequency	f <sub>TO</sub>	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V					12	MHz
		2.7 V ≤ V <sub>DD</sub> < 4.0 V					8	MHz
		1.8 V ≤ V <sub>DD</sub> < 2.7 V					4	MHz
PCLBUZ0, or PCLBUZ1 output frequency	f <sub>PCL</sub>	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V					16	MHz
		2.7 V ≤ V <sub>DD</sub> < 4.0 V					8	MHz
		1.8 V ≤ V <sub>DD</sub> < 2.7 V					4	MHz
INTP0 to INTP5 input high-level width, low-level width	t <sub>INTH</sub> , t <sub>INTL</sub>				1			μs
KR0 to KR9 input available width	t <sub>KR</sub>				250			ns
RESET low-level width	t <sub>RSL</sub>				10			μs

**Remark** fMCK: Timer array unit operation clock frequency

(Operation clock to be set by the timer clock select register 0 (TPS0) and the CKS0n bit of timer mode register 0n (TMR0n). n: Channel number (n = 0 to 7))

(2) During communication at same potential (CSI mode) (master mode, SCK00... internal clock output, corresponding CSI00 only)

(T<sub>A</sub> = –40 to +85°C, 2.7 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	
SCK00 cycle time	t <sub>KCY1</sub>	t <sub>KCY1</sub> ≥ 2/f <sub>CLK</sub>	83.3		250		ns
SCK00 high-/low-level width	t <sub>KH1</sub> , t <sub>KL1</sub>	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V	t <sub>KCY1</sub> /2–7		t <sub>KCY1</sub> /2–50		ns
		2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	t <sub>KCY1</sub> /2–10		t <sub>KCY1</sub> /2–50		ns
SI00 setup time (to SCK00↑) <sup>Note 1</sup>	t <sub>SIK1</sub>	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V	23		110		ns
		2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	33		110		ns
SI00 hold time (from SCK00↑) <sup>Note 2</sup>	t <sub>KSI1</sub>		10		10		ns
Delay time from SCK00↓ to SO00 output <sup>Note 3</sup>	t <sub>KSO1</sub>	C = 20 pF <sup>Note 4</sup>		10		10	ns

- Notes**
1. When DAP00 = 0 and CKP00 = 0, or DAP00 = 1 and CKP00 = 1. The SI00 setup time becomes “to SCK00↓” when DAP00 = 0 and CKP00 = 1, or DAP00 = 1 and CKP00 = 0.
  2. When DAP00 = 0 and CKP00 = 0, or DAP00 = 1 and CKP00 = 1. The SI00 hold time becomes “from SCK00↓” when DAP00 = 0 and CKP00 = 1, or DAP00 = 1 and CKP00 = 0.
  3. When DAP00 = 0 and CKP00 = 0, or DAP00 = 1 and CKP00 = 1. The delay time to SO00 output becomes “from SCK00↑” when DAP00 = 0 and CKP00 = 1, or DAP00 = 1 and CKP00 = 0.
  4. C is the load capacitance of the SCK00 and SO00 output lines.

**Caution** Select the normal input buffer for the SI00 pin and the normal output mode for the SO00 and SCK00 pins by using port input mode register 1 (PIM1) and port output mode register 1 (POM1).

- Remarks**
1. This specification is valid only when CSI00's peripheral I/O redirect function is not used.
  2. f<sub>MCK</sub>: Serial array unit operation clock frequency  
(Operation clock to be set by the serial clock select register 0 (SPS0) and the CKS00 bit of serial mode register 00 (SMR00).)

**(3) During communication at same potential (CSI mode) (master mode, SCKp... internal clock output)****(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)**

Parameter	Symbol	Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		Unit
				MIN.	MAX.	MIN.	MAX.	
SCKp cycle time	t <sub>KCY1</sub>	t <sub>KCY1</sub> ≥ 4/f <sub>CLK</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	167		500		ns
			2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	250		500		ns
			1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V	—		500		ns
SCKp high-/low-level width	t <sub>KH1</sub> , t <sub>KL1</sub>	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V		t <sub>KCY1</sub> /2–12		t <sub>KCY1</sub> /2–50		ns
		2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V		t <sub>KCY1</sub> /2–18		t <sub>KCY1</sub> /2–50		ns
		2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V		t <sub>KCY1</sub> /2–38		t <sub>KCY1</sub> /2–50		ns
		1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V		—		t <sub>KCY1</sub> /2–50		ns
Slp setup time (to SCKp↑) <small>Note 1</small>	t <sub>SIK1</sub>	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V		44		110		ns
		2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V		44		110		ns
		2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V		75		110		ns
		1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V		—		110		ns
Slp hold time (from SCKp↑) <small>Note 2</small>	t <sub>SH1</sub>			19		19		ns
Delay time from SCKp↓ to SOp output <small>Note 3</small>	t <sub>KSO1</sub>	C = 30 pF <small>Note 4</small>			25		25	ns

- Notes**
1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes “to SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
  2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
  3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
  4. C is the load capacitance of the SCKp and SOp output lines.

**Caution** Select the normal input buffer for the Slp pin and the normal output mode for the SOp and SCKp pins by using port input mode register 1 (PIM1) and port output mode registers 0, 1, 4 (POM0, POM1, POM4).

- Remarks**
1. p: CSI number (p = 00, 01, 11, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 1, 3: “1, 3” is only for the R5F102 products)
  2. f<sub>MCK</sub>: Serial array unit operation clock frequency  
(Operation clock to be set by the serial clock select register m (SPSm) and the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0, 1), n: Channel number (n = 0, 1, 3: “1, 3” is only for the R5F102 products.))

**(4) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input)****( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		Unit
				MIN.	MAX.	MIN.	MAX.	
SCKp cycle time <sup>Note 4</sup>	$t_{KCY2}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	$20\text{ MHz} < f_{MCK}$	$8/f_{MCK}$		—		ns
			$f_{MCK} \leq 20\text{ MHz}$	$6/f_{MCK}$		$6/f_{MCK}$		ns
		$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	$16\text{ MHz} < f_{MCK}$	$8/f_{MCK}$		—		ns
			$f_{MCK} \leq 16\text{ MHz}$	$6/f_{MCK}$		$6/f_{MCK}$		ns
		$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		$6/f_{MCK}$ and 500		$6/f_{MCK}$ and 500		ns
		$1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		—		$6/f_{MCK}$ and 750		ns
SCKp high-/low-level width	$t_{KH2}$ , $t_{KL2}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		$t_{KCY2}/2-7$		$t_{KCY2}/2-7$		ns
		$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		$t_{KCY2}/2-8$		$t_{KCY2}/2-8$		ns
		$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		$t_{KCY2}/2-18$		$t_{KCY2}/2-18$		ns
		$1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		—		$t_{KCY2}/2-18$		ns
Slp setup time (to SCKp $\uparrow$ ) <sup>Note 1</sup>	$t_{SIK2}$	$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		$1/f_{MCK} + 20$		$1/f_{MCK} + 30$		ns
		$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		$1/f_{MCK} + 30$		$1/f_{MCK} + 30$		ns
		$1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		—		$1/f_{MCK} + 30$		ns
Slp hold time (from SCKp $\uparrow$ ) <sup>Note 2</sup>	$t_{KSI2}$			$1/f_{MCK} + 31$		$1/f_{MCK} + 31$		ns
Delay time from SCKp $\downarrow$ to SOp output <sup>Note 3</sup>	$t_{KSO2}$	$C = 30\text{ pF}$ <sup>Note 4</sup>	$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		$2/f_{MCK} + 44$		$2/f_{MCK} + 110$	ns
			$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		$2/f_{MCK} + 75$		$2/f_{MCK} + 110$	ns
			$1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$		—		$2/f_{MCK} + 110$	ns

- Notes**
1. When  $DAPmn = 0$  and  $CKPmn = 0$ , or  $DAPmn = 1$  and  $CKPmn = 1$ . The Slp setup time becomes “to SCKp $\downarrow$ ” when  $DAPmn = 0$  and  $CKPmn = 1$ , or  $DAPmn = 1$  and  $CKPmn = 0$ .
  2. When  $DAPmn = 0$  and  $CKPmn = 0$ , or  $DAPmn = 1$  and  $CKPmn = 1$ . The Slp hold time becomes “from SCKp $\downarrow$ ” when  $DAPmn = 0$  and  $CKPmn = 1$ , or  $DAPmn = 1$  and  $CKPmn = 0$ .
  3. When  $DAPmn = 0$  and  $CKPmn = 0$ , or  $DAPmn = 1$  and  $CKPmn = 1$ . The delay time to SOp output becomes “from SCKp $\uparrow$ ” when  $DAPmn = 0$  and  $CKPmn = 1$ , or  $DAPmn = 1$  and  $CKPmn = 0$ .
  4. C is the load capacitance of the SOp output lines.
  5. Transfer rate in the SNOOZE mode: MAX. 1 Mbps

**Caution** Select the normal input buffer for the Slp and SCKp pins and the normal output mode for the SOp pin by using port input mode register 1 (PIM1) and port output mode registers 0, 1, 4 (POM0, POM1, POM4).

**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)****(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	
Transfer rate <small>Note4</small>		Reception	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V			f <sub>MCK</sub> /6 <small>Note1</small>	bps
			Theoretical value of the maximum transfer rate f <sub>MCK</sub> = f <sub>CLK</sub> <small>Note3</small>			4.0	Mbps
			2.7 V ≤ V <sub>DD</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V			f <sub>MCK</sub> /6 <small>Note1</small>	bps
			Theoretical value of the maximum transfer rate f <sub>MCK</sub> = f <sub>CLK</sub> <small>Note3</small>			4.0	Mbps
			1.8 V ≤ V <sub>DD</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V			f <sub>MCK</sub> /6 <small>Notes1, 2</small>	bps
			Theoretical value of the maximum transfer rate f <sub>MCK</sub> = f <sub>CLK</sub> <small>Note3</small>			4.0	Mbps
		Transmission	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V			<b>Note4</b>	bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 1.4 kΩ, V <sub>b</sub> = 2.7 V			2.8 <small>Note5</small>	Mbps
			2.7 V ≤ V <sub>DD</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V,			<b>Note6</b>	bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ, V <sub>b</sub> = 2.3 V			1.2 <small>Note7</small>	Mbps
			1.8 V ≤ V <sub>DD</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V			<b>Notes 2, 8</b>	bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 5.5 kΩ, V <sub>b</sub> = 1.6 V			0.43 <small>Note9</small>	Mbps

**Notes** 1. Transfer rate in the SNOOZE mode is 4800 bps only.2. Use it with V<sub>DD</sub> ≥ V<sub>b</sub>.3. The maximum operating frequencies of the CPU/peripheral hardware clock (f<sub>CLK</sub>) are:HS (high-speed main) mode: 24 MHz (2.7 V ≤ V<sub>DD</sub> ≤ 5.5 V)16 MHz (2.4 V ≤ V<sub>DD</sub> ≤ 5.5 V)LS (low-speed main) mode: 8 MHz (1.8 V ≤ V<sub>DD</sub> ≤ 5.5 V)4. The smaller maximum transfer rate derived by using f<sub>MCK</sub>/6 or the following expression is the valid maximum transfer rate.Expression for calculating the transfer rate when 4.0 V ≤ V<sub>DD</sub> ≤ 5.5 V and 2.7 V ≤ V<sub>b</sub> ≤ 4.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\} \times 3} \quad [\text{bps}]$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 [\%]$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides.

**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (1/3)****( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		Unit
				MIN.	MAX.	MIN.	MAX.	
SCKp cycle time	$t_{KCY1}$	$t_{KCY1} \geq 4/f_{CLK}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	300		1150		ns
			$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	500		1150		ns
			$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}^{\text{Note}}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	1150		1150		ns
SCKp high-level width	$t_{KH1}$		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	$t_{KCY1}/2 - 75$		$t_{KCY1}/2 - 75$		ns
			$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	$t_{KCY1}/2 - 170$		$t_{KCY1}/2 - 170$		ns
			$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}^{\text{Note}}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	$t_{KCY1}/2 - 458$		$t_{KCY1}/2 - 458$		ns
SCKp low-level width	$t_{KL1}$		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	$t_{KCY1}/2 - 12$		$t_{KCY1}/2 - 50$		ns
			$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	$t_{KCY1}/2 - 18$		$t_{KCY1}/2 - 50$		ns
			$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}^{\text{Note}}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	$t_{KCY1}/2 - 50$		$t_{KCY1}/2 - 50$		ns

**Note** Use it with  $V_{DD} \geq V_b$ .

**Cautions 1.** Select the TTL input buffer for the SIp pin and the N-ch open drain output ( $V_{DD}$  tolerance) mode for the SOp pin and SCKp pin by using port input mode register 1 (PIM1) and port output mode register 1 (POM1). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

**2.** CSI01 and CSI11 cannot communicate at different potential.

**Remarks 1.**  $R_b$  [ $\Omega$ ]: Communication line (SCKp, SOp) pull-up resistance,  $C_b$  [F]: Communication line (SCKp, SOp) load capacitance,  $V_b$  [V]: Communication line voltage

**2.** p: CSI number (p = 00, 20)



## 2.6.2 Temperature sensor/internal reference voltage characteristics

**( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ , HS (high-speed main) mode)**

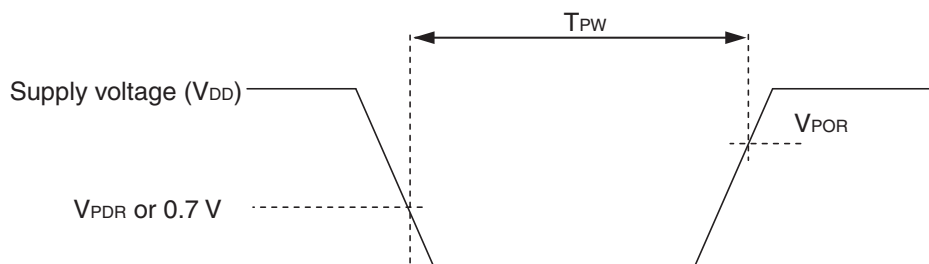
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Temperature sensor output voltage	$V_{TMPS25}$	Setting ADS register = 80H, $T_A = +25^\circ\text{C}$		1.05		V
Internal reference voltage	$V_{BGR}$	Setting ADS register = 81H	1.38	1.45	1.50	V
Temperature coefficient	$F_{VTMPS}$	Temperature sensor output voltage that depends on the temperature		-3.6		mV/ $^\circ\text{C}$
Operation stabilization wait time	$t_{AMP}$		5			$\mu\text{s}$

## 2.6.3 POR circuit characteristics

**( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Detection voltage	$V_{POR}$	Power supply rise time	1.47	1.51	1.55	V
	$V_{PDR}$	Power supply fall time	1.46	1.50	1.54	V
Minimum pulse width <sup>Note</sup>	$T_{PW}$		300			$\mu\text{s}$

**Note** Minimum time required for a POR reset when  $V_{DD}$  exceeds below  $V_{PDR}$ . This is also the minimum time required for a POR reset from when  $V_{DD}$  exceeds below 0.7 V to when  $V_{DD}$  exceeds  $V_{POR}$  while STOP mode is entered or the main system clock is stopped through setting bit 0 (HIOSTOP) and bit 7 (MSTOP) in the clock operation status control register (CSC).



## 2.6.4 LVD circuit characteristics

## LVD Detection Voltage of Reset Mode and Interrupt Mode

(T<sub>A</sub> = -40 to +85°C, V<sub>PDR</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

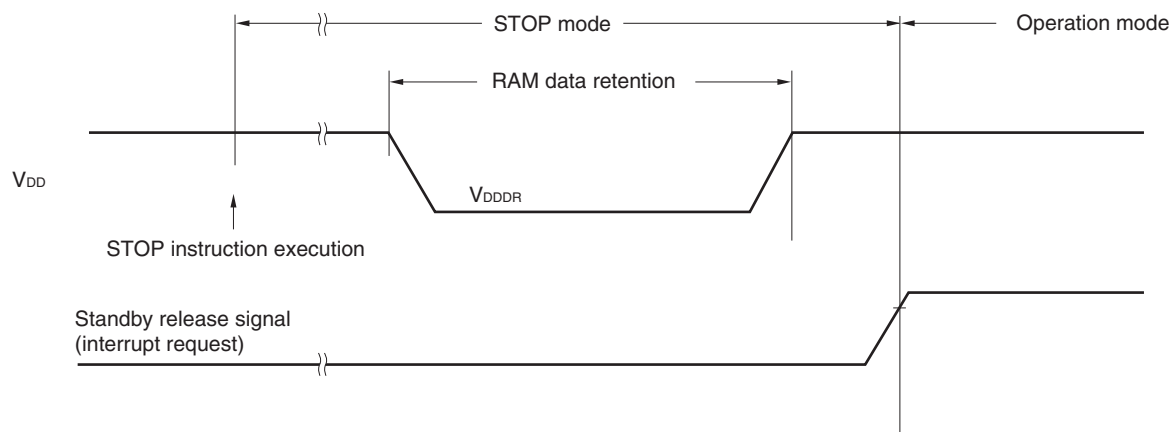
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Detection supply voltage	V <sub>LVD0</sub>	Power supply rise time	3.98	4.06	4.14	V
		Power supply fall time	3.90	3.98	4.06	V
	V <sub>LVD1</sub>	Power supply rise time	3.68	3.75	3.82	V
		Power supply fall time	3.60	3.67	3.74	V
	V <sub>LVD2</sub>	Power supply rise time	3.07	3.13	3.19	V
		Power supply fall time	3.00	3.06	3.12	V
	V <sub>LVD3</sub>	Power supply rise time	2.96	3.02	3.08	V
		Power supply fall time	2.90	2.96	3.02	V
	V <sub>LVD4</sub>	Power supply rise time	2.86	2.92	2.97	V
		Power supply fall time	2.80	2.86	2.91	V
	V <sub>LVD5</sub>	Power supply rise time	2.76	2.81	2.87	V
		Power supply fall time	2.70	2.75	2.81	V
	V <sub>LVD6</sub>	Power supply rise time	2.66	2.71	2.76	V
		Power supply fall time	2.60	2.65	2.70	V
	V <sub>LVD7</sub>	Power supply rise time	2.56	2.61	2.66	V
		Power supply fall time	2.50	2.55	2.60	V
	V <sub>LVD8</sub>	Power supply rise time	2.45	2.50	2.55	V
		Power supply fall time	2.40	2.45	2.50	V
	V <sub>LVD9</sub>	Power supply rise time	2.05	2.09	2.13	V
		Power supply fall time	2.00	2.04	2.08	V
	V <sub>LVD10</sub>	Power supply rise time	1.94	1.98	2.02	V
		Power supply fall time	1.90	1.94	1.98	V
	V <sub>LVD11</sub>	Power supply rise time	1.84	1.88	1.91	V
		Power supply fall time	1.80	1.84	1.87	V
Minimum pulse width	t <sub>LW</sub>		300			μs
Detection delay time					300	μs

## &lt;R&gt; 2.7 Data Memory STOP Mode Low Supply Voltage Data Retention Characteristics

**( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention supply voltage	$V_{DDDR}$		1.46 <sup>Note</sup>		5.5	V

<R> **Note** This depends on the POR detection voltage. For a falling voltage, data in RAM are retained until the voltage reaches the level that triggers a POR reset but not once it reaches the level at which a POR reset is generated.



## 2.8 Flash Memory Programming Characteristics

**( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

<R>	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
	System clock frequency	f <sub>CLK</sub>		1		24	MHz
	Code flash memory rewritable times <small>Notes 1, 2, 3</small>	C <sub>erwr</sub>	Retained for 20 years T <sub>A</sub> = 85°C	1,000			Times
	Data flash memory rewritable times <small>Notes 1, 2, 3</small>		Retained for 1 year T <sub>A</sub> = 25°C		1,000,000		
			Retained for 5 years T <sub>A</sub> = 85°C	100,000			
			Retained for 20 years T <sub>A</sub> = 85°C	10,000			

- Notes**
- 1 erase + 1 write after the erase is regarded as 1 rewrite. The retaining years are until next rewrite after the rewrite.
  2. When using flash memory programmer and Renesas Electronics self programming library
  3. These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.

## 2.9 Dedicated Flash Memory Programmer Communication (UART)

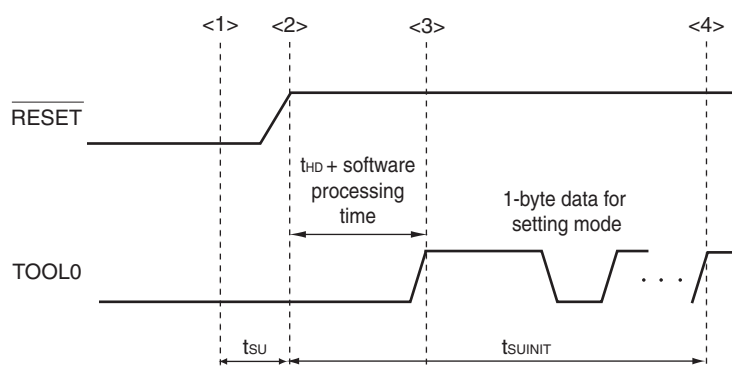
**( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate		During serial programming	115,200		1,000,000	bps

## 2.10 Timing of Entry to Flash Memory Programming Modes

**( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Time to complete the communication for the initial setting after the external reset is released	$t_{\text{SUNIT}}$	POR and LVD reset are released before external reset release			100	ms
Time to release the external reset after the TOOL0 pin is set to the low level	$t_{\text{SU}}$	POR and LVD reset are released before external reset release	10			$\mu\text{s}$
Time to hold the TOOL0 pin at the low level after the external reset is released (excluding the processing time of the firmware to control the flash memory)	$t_{\text{HD}}$	POR and LVD reset are released before external reset release	1			ms



- <1> The low level is input to the TOOL0 pin.
- <2> The external reset is released (POR and LVD reset must be released before the external reset is released.).
- <3> The TOOL0 pin is set to the high level.
- <4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

**Remark**  $t_{\text{SUNIT}}$ : Communication for the initial setting must be completed within 100 ms after the external reset is released during this period.

$t_{\text{SU}}$ : Time to release the external reset after the TOOL0 pin is set to the low level

$t_{\text{HD}}$ : Time to hold the TOOL0 pin at the low level after the external reset is released (excluding the processing time of the firmware to control the flash memory)

## 3.3.2 Supply current characteristics

## (1) 20-, 24-pin products

 $(T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V})$ 

(1/2)

Parameter	Symbol	Conditions					MIN.	TYP.	MAX.	Unit
Supply current <sup>Note 1</sup>	I <sub>DD1</sub>	Operating mode	HS (High-speed main) mode <sup>Note 4</sup>	$f_{IH} = 24\text{ MHz}$ <sup>Note 3</sup>	Basic operation	$V_{DD} = 5.0\text{ V}$		1.5		mA
						$V_{DD} = 3.0\text{ V}$		1.5		
					Normal operation	$V_{DD} = 5.0\text{ V}$		3.3	5.3	mA
						$V_{DD} = 3.0\text{ V}$		3.3	5.3	
				$f_{IH} = 16\text{ MHz}$ <sup>Note 3</sup>		$V_{DD} = 5.0\text{ V}$		2.5	3.9	mA
						$V_{DD} = 3.0\text{ V}$		2.5	3.9	
				$f_{MX} = 20\text{ MHz}$ <sup>Note 2</sup> , $V_{DD} = 5.0\text{ V}$		Square wave input		2.8	4.7	mA
						Resonator connection		3.0	4.8	
				$f_{MX} = 20\text{ MHz}$ <sup>Note 2</sup> , $V_{DD} = 3.0\text{ V}$		Square wave input		2.8	4.7	mA
						Resonator connection		3.0	4.8	
				$f_{MX} = 10\text{ MHz}$ <sup>Note 2</sup> , $V_{DD} = 5.0\text{ V}$		Square wave input		1.8	2.8	mA
						Resonator connection		1.8	2.8	
				$f_{MX} = 10\text{ MHz}$ <sup>Note 2</sup> , $V_{DD} = 3.0\text{ V}$		Square wave input		1.8	2.8	mA
						Resonator connection		1.8	2.8	

- Notes**
1. Total current flowing into  $V_{DD}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$  or  $V_{SS}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. When high-speed on-chip oscillator clock is stopped.
  3. When high-speed system clock is stopped
  4. Relationship between operation voltage width, operation frequency of CPU and operation mode is as follows.

HS(High speed main) mode:  $V_{DD} = 2.7\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $24\text{ MHz}$  $V_{DD} = 2.4\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $16\text{ MHz}$ 

- Remarks**
1.  $f_{MX}$ : High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  2.  $f_{IH}$ : high-speed on-chip oscillator clock frequency
  3. Temperature condition of the TYP. value is  $T_A = 25^\circ\text{C}$ .

**(3) Peripheral functions (Common to all products)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Low-speed onchip oscillator operating current	$I_{FIL}$ <sup>Note 1</sup>				0.20		$\mu\text{A}$
12-bit interval timer operating current	$I_{TMKA}$ <sup>Notes 1, 2, 3</sup>				0.02		$\mu\text{A}$
Watchdog timer operating current	$I_{WDT}$ <sup>Notes 1, 2, 4</sup>	$f_{IL} = 15\text{ kHz}$			0.22		$\mu\text{A}$
A/D converter operating current	$I_{ADC}$ <sup>Notes 1, 5</sup>	When conversion at maximum speed	Normal mode, $AV_{REFP} = V_{DD} = 5.0\text{ V}$		1.30	1.70	mA
			Low voltage mode, $AV_{REFP} = V_{DD} = 3.0\text{ V}$		0.50	0.70	mA
A/D converter reference voltage operating current	$I_{ADREF}$ <sup>Note 1</sup>				75.0		$\mu\text{A}$
Temperature sensor operating current	$I_{TMPS}$ <sup>Note 1</sup>				75.0		$\mu\text{A}$
LVD operating current	$I_{LVD}$ <sup>Notes 1, 6</sup>				0.08		$\mu\text{A}$
Self-programming operating current	$I_{FSP}$ <sup>Notes 1, 8</sup>				2.00	12.20	mA
BGO operating current	$I_{BGO}$ <sup>Notes 1, 7</sup>				2.00	12.20	mA
SNOOZE operating current	$I_{SNOZ}$ <sup>Note 1</sup>	ADC operation	The mode is performed <sup>Note 9</sup>		0.50	1.10	mA
			The A/D conversion operations are performed, Low voltage mode, $AV_{REFP} = V_{DD} = 3.0\text{ V}$		1.20	2.04	mA
		CSI/UART operation			0.70	1.54	mA

**Notes** 1. Current flowing to the  $V_{DD}$ .

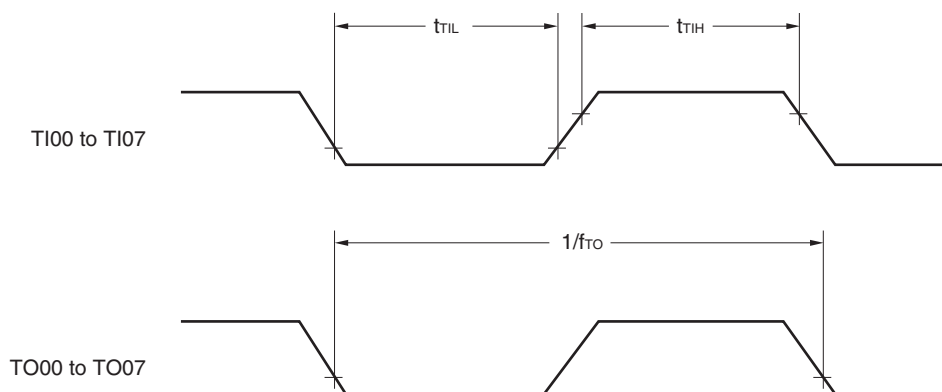
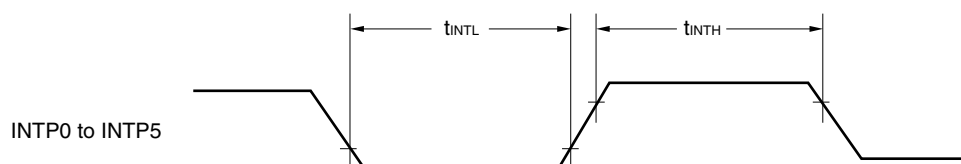
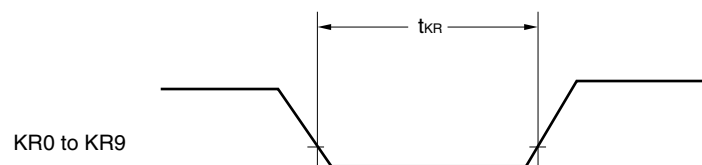
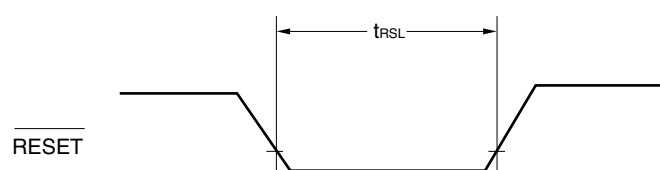
2. When high speed on-chip oscillator and high-speed system clock are stopped.

3. Current flowing only to the 12-bit interval timer (excluding the operating current of the low-speed on-chip oscillator). The current value of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$  or  $I_{DD3}$ , and  $I_{FIL}$  and  $I_{TMKA}$  when the 12-bit interval timer operates.4. Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator). The current value of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$  or  $I_{DD3}$  and  $I_{WDT}$  when the watchdog timer operates.5. Current flowing only to the A/D converter. The current value of the RL78 microcontrollers is the sum of  $I_{DD1}$  or  $I_{DD2}$  and  $I_{ADC}$  when the A/D converter operates in an operation mode or the HALT mode.6. Current flowing only to the LVD circuit. The current value of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$  or  $I_{DD3}$  and  $I_{LVD}$  when the LVD circuit operates.

7. Current flowing only during data flash rewrite.

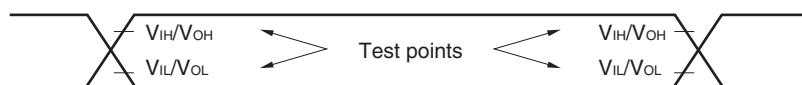
8. Current flowing only during self programming.

9. For shift time to the SNOOZE mode, see **17.3.3 SNOOZE mode**.**Remarks** 1.  $f_{IL}$ : Low-speed on-chip oscillator clock frequency2. Temperature condition of the TYP. value is  $T_A = 25^\circ\text{C}$

**TI/TO Timing****Interrupt Request Input Timing****Key Interrupt Input Timing****RESET Input Timing**

### 3.5 Peripheral Functions Characteristics

#### AC Timing Test Point



#### 3.5.1 Serial array unit

##### (1) During communication at same potential (UART mode)

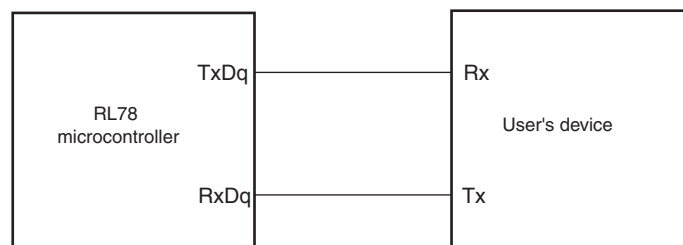
( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
Transfer rate <small>Note 1</small>		Theoretical value of the maximum transfer rate $f_{CLK} = f_{MCK}$ <small>Note2</small>		$f_{MCK}/12$	bps
				2.0	Mbps

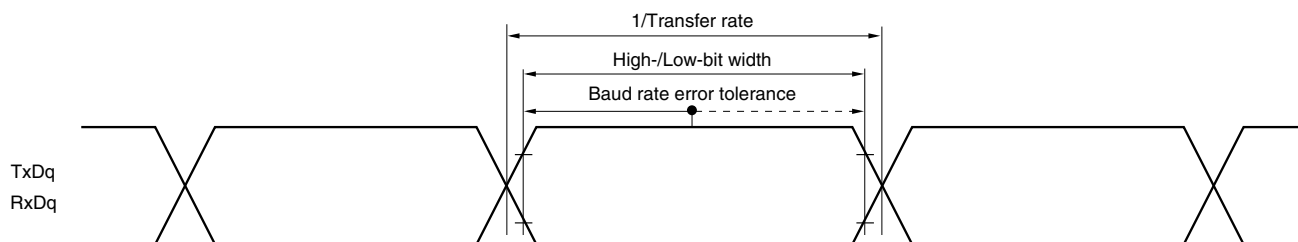
- Notes**
- Transfer rate in the SNOOZE mode is 4800 bps only.
  - The maximum operating frequencies of the CPU/peripheral hardware clock ( $f_{CLK}$ ) are:  
 HS (high-speed main) mode: 24 MHz ( $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ )  
 16 MHz ( $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ )

**Caution** Select the normal input buffer for the RxDq pin and the normal output mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

#### UART mode connection diagram (during communication at same potential)



#### UART mode bit width (during communication at same potential) (reference)



- Remarks**
- q: UART number (q = 0 to 2), g: PIM, POM number (g = 0, 1)
  - $f_{MCK}$ : Serial array unit operation clock frequency  
 (Operation clock to be set by the serial clock select register m (SPSm) and the CKSmn bit of serial mode register mn (SMRmn).  
 m: Unit number, n: Channel number (mn = 00 to 03, 10, 11))



**(2) During communication at same potential (CSI mode) (master mode, SCKp... internal clock output)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
SCKp cycle time	$t_{KCY1}$	$t_{KCY1} \geq 4/f_{CLK}$	$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	334	ns
			$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	500	ns
SCKp high-/low-level width	$t_{KH1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	$t_{KCY1}/2-24$		ns
	$t_{KL1}$	$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	$t_{KCY1}/2-36$		ns
		$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	$t_{KCY1}/2-76$		ns
Slp setup time (to SCKp $\uparrow$ ) <sup>Note 1</sup>	$t_{SIK1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	66		ns
		$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	66		ns
		$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	113		ns
Slp hold time (from SCKp $\uparrow$ ) <sup>Note 2</sup>	$t_{KSI1}$		38		ns
Delay time from SCKp $\downarrow$ to SOp output <sup>Note 3</sup>	$t_{KSO1}$	$C = 30\text{ pF}$ <sup>Note 4</sup>		50	ns

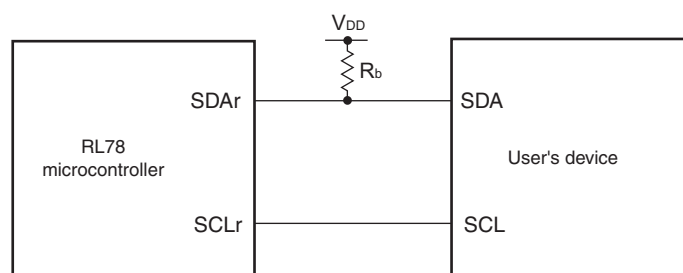
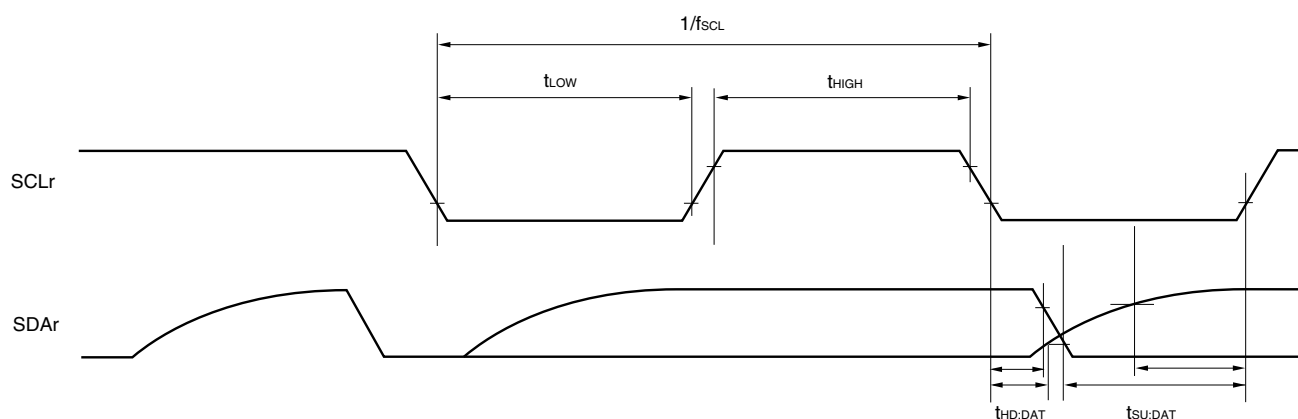
- Notes**
1. When  $DAPmn = 0$  and  $CKPmn = 0$ , or  $DAPmn = 1$  and  $CKPmn = 1$ . The Slp setup time becomes “to SCKp $\downarrow$ ” when  $DAPmn = 0$  and  $CKPmn = 1$ , or  $DAPmn = 1$  and  $CKPmn = 0$ .
  2. When  $DAPmn = 0$  and  $CKPmn = 0$ , or  $DAPmn = 1$  and  $CKPmn = 1$ . The Slp hold time becomes “from SCKp $\downarrow$ ” when  $DAPmn = 0$  and  $CKPmn = 1$ , or  $DAPmn = 1$  and  $CKPmn = 0$ .
  3. When  $DAPmn = 0$  and  $CKPmn = 0$ , or  $DAPmn = 1$  and  $CKPmn = 1$ . The delay time to SOp output becomes “from SCKp $\uparrow$ ” when  $DAPmn = 0$  and  $CKPmn = 1$ , or  $DAPmn = 1$  and  $CKPmn = 0$ .
  4. C is the load capacitance of the SCKp and SOp output lines.

**Caution** Select the normal input buffer for the Slp pin and the normal output mode for the SOp and SCKp pins by using port input mode register 1 (PIM1) and port output mode registers 0, 1, 4 (POM0, POM1, POM4).

- Remarks**
1. p: CSI number (p = 00, 01, 11, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 1, 3)
  2.  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the serial clock select register m (SPSm) and the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0, 1), n: Channel number (n = 0, 1, 3))

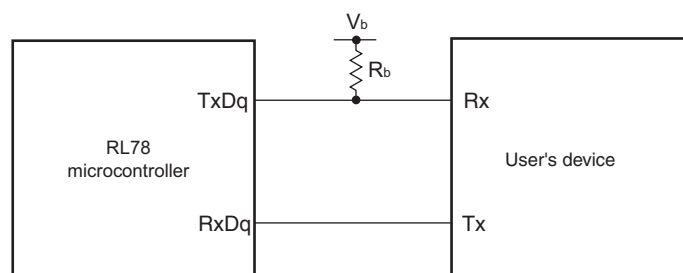
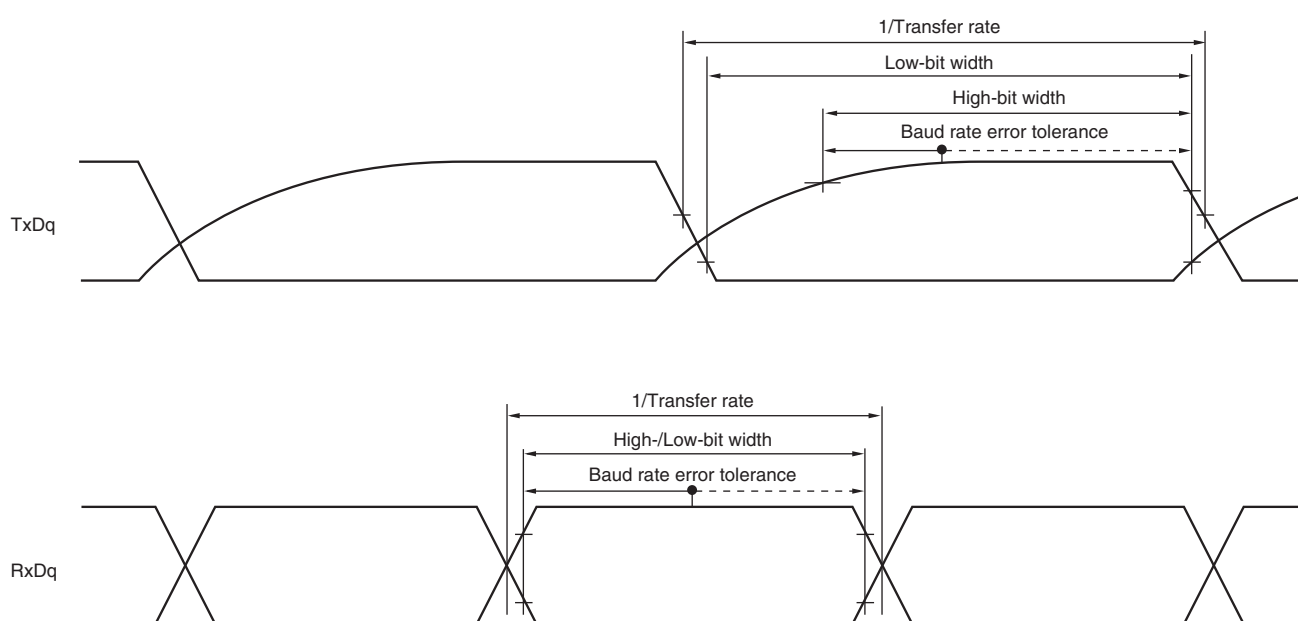
**(4) During communication at same potential (simplified I<sup>2</sup>C mode)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
SCLr clock frequency	$f_{\text{SCL}}$	$C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$		100 <sup>Note 1</sup>	kHz
Hold time when SCLr = "L"	$t_{\text{LOW}}$	$C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	4600		ns
Hold time when SCLr = "H"	$t_{\text{HIGH}}$	$C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	4600		ns
Data setup time (reception)	$t_{\text{SU:DAT}}$	$C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	$1/f_{\text{MCK}} + 580$ <sup>Note 2</sup>		ns
Data hold time (transmission)	$t_{\text{HD:DAT}}$	$C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	0	1420	ns

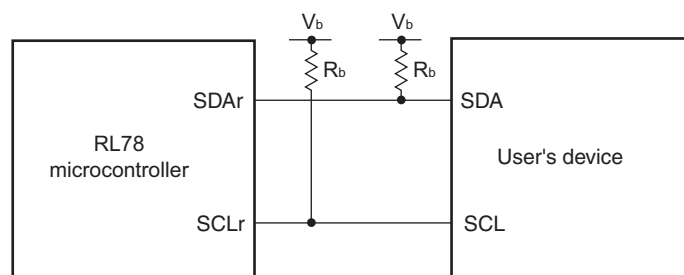
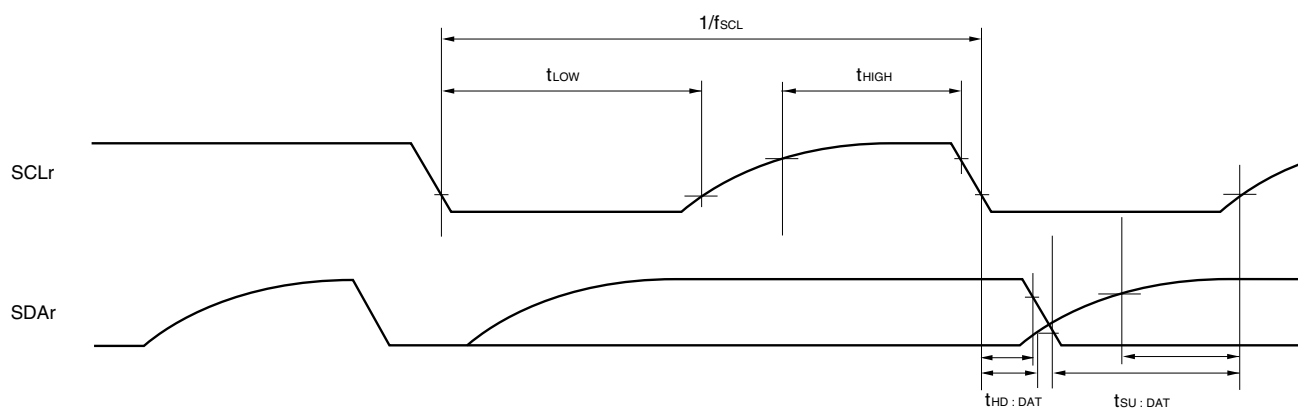
**Notes 1.** The value must also be equal to or less than  $f_{\text{MCK}}/4$ .**2.** Set  $t_{\text{SU:DAT}}$  so that it will not exceed the hold time when SCLr = "L" or SCLr = "H".**Caution** Select the N-ch open drain output ( $V_{DD}$  tolerance) mode for SDAr by using port output mode register h (POMh).**Simplified I<sup>2</sup>C mode connection diagram (during communication at same potential)****Simplified I<sup>2</sup>C mode serial transfer timing (during communication at same potential)****Remarks 1.**  $R_b$  [ $\Omega$ ]: Communication line (SDAr) pull-up resistance $C_b$  [F]: Communication line (SCLr, SDAr) load capacitance**2.** r: IIC number (r = 00, 01, 11, 20), h: = POM number (h = 0, 1, 4, 5)**3.**  $f_{\text{MCK}}$ : Serial array unit operation clock frequency

(Operation clock to be set by the serial clock select register m (SPSm) and the CKSmn bit of serial mode register mn (SMRmn).

m: Unit number (m = 0, 1), n: Channel number (0, 1, 3))

**UART mode connection diagram (during communication at different potential)****UART mode bit width (during communication at different potential) (reference)**

- Remarks**
1.  $R_b[\Omega]$ : Communication line (TxDq) pull-up resistance,  $C_b[\text{F}]$ : Communication line (TxDq) load capacitance,  $V_b[\text{V}]$ : Communication line voltage
  2. q: UART number (q = 0 to 2), g: PIM and POM number (g = 0, 1)
  3.  $f_{\text{MCK}}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the serial clock select register m (SPSm) and the CKSmn bit of serial mode register mn (SMRmn).  
m: Unit number, n: Channel number (mn = 00 to 03, 10, 11))
  4. UART0 of the 20- and 24-pin products supports communication at different potential only when the peripheral I/O redirection function is not used.

**Simplified I<sup>2</sup>C mode connection diagram (during communication at different potential)****Simplified I<sup>2</sup>C mode serial transfer timing (during communication at different potential)**

- Remarks 1.**  $R_b$  [ $\Omega$ ]: Communication line (SDAr, SCLr) pull-up resistance,  $C_b$  [F]: Communication line (SDAr, SCLr) load capacitance,  $V_b$  [V]: Communication line voltage
- 2.**  $r$ : IIC Number ( $r = 00, 20$ )
- 3.**  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the serial clock select register  $m$  (SPS $m$ ) and the CKS $m$  $n$  bit of serial mode register  $m$  $n$  (SMR $m$  $n$ ).  
 $m$ : Unit number ( $m = 0, 1$ ),  $n$ : Channel number ( $n = 0$ ))

Rev.	Date	Description	
		Page	Summary
2.00	Sep 06, 2013	55	Modification of description and Notes 3 and 4 in 2.6.1 (3)
		56	Modification of description and Notes 3 and 4 in 2.6.1 (4)
		57	Modification of table in 2.6.2 Temperature sensor/internal reference voltage characteristics
		57	Modification of table and Note in 2.6.3 POR circuit characteristics
		58	Modification of table in 2.6.4 LVD circuit characteristics
		59	Modification of table of LVD detection voltage of interrupt & reset mode
		59	Modification of number and title to 2.6.5 Power supply voltage rising slope characteristics
		61	Modification of table, figure, and Remark in 2.10 Timing of Entry to Flash Memory Programming Modes
		62 to 103	Addition of products of industrial applications (G: T <sub>A</sub> = -40 to +105°C)
		104 to 106	Addition of products of industrial applications (G: T <sub>A</sub> = -40 to +105°C)
2.10	Mar 25, 2016	6	Modification of Figure 1-1 Part Number, Memory Size, and Package of RL78/G12
		7	Modification of Table 1-1 List of Ordering Part Numbers
		8	Addition of product name (RL78/G12) and description (Top View) in 1.4.1 20-pin products
		9	Addition of product name (RL78/G12) and description (Top View) in 1.4.2 24-pin products
		10	Addition of product name (RL78/G12) and description (Top View) in 1.4.3 30-pin products
		15	Modification of description in 1.7 Outline of Functions
		16	Modification of description, and addition of target products
		52	Modification of note 2 in 2.5.2 Serial interface IICA
		60	Modification of title and note, and addition of caution in 2.7 RAM Data Retention Characteristics
		60	Modification of conditions in 2.8 Flash Memory Programming Characteristics
		62	Modification of description, and addition of target products and remark
		94	Modification of note 2 in 3.5.2 Serial interface IICA
		102	Modification of title and note in 3.7 RAM Data Retention Characteristics
		102	Modification of conditions in 3.8 Flash Memory Programming Characteristics
		104 to 106	Addition of package name

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